

Technology of photovoltaic cells and modules

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Clean Energy Expo Asia 2010
Singapore, 2 Nov 2010

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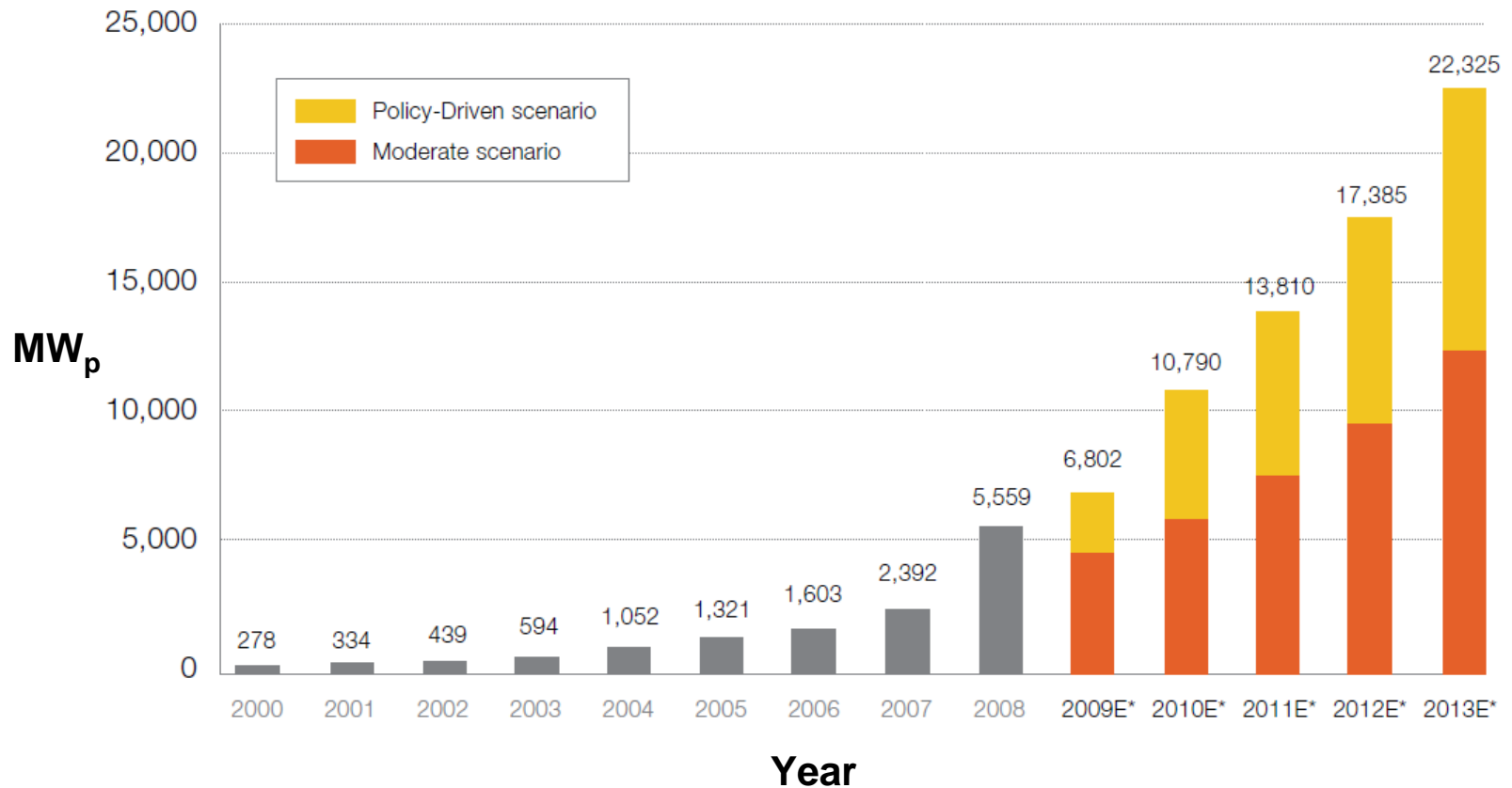
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Outline

1. Market leading PV technologies
2. Silicon wafer PV
3. Thin-film PV
4. Summary

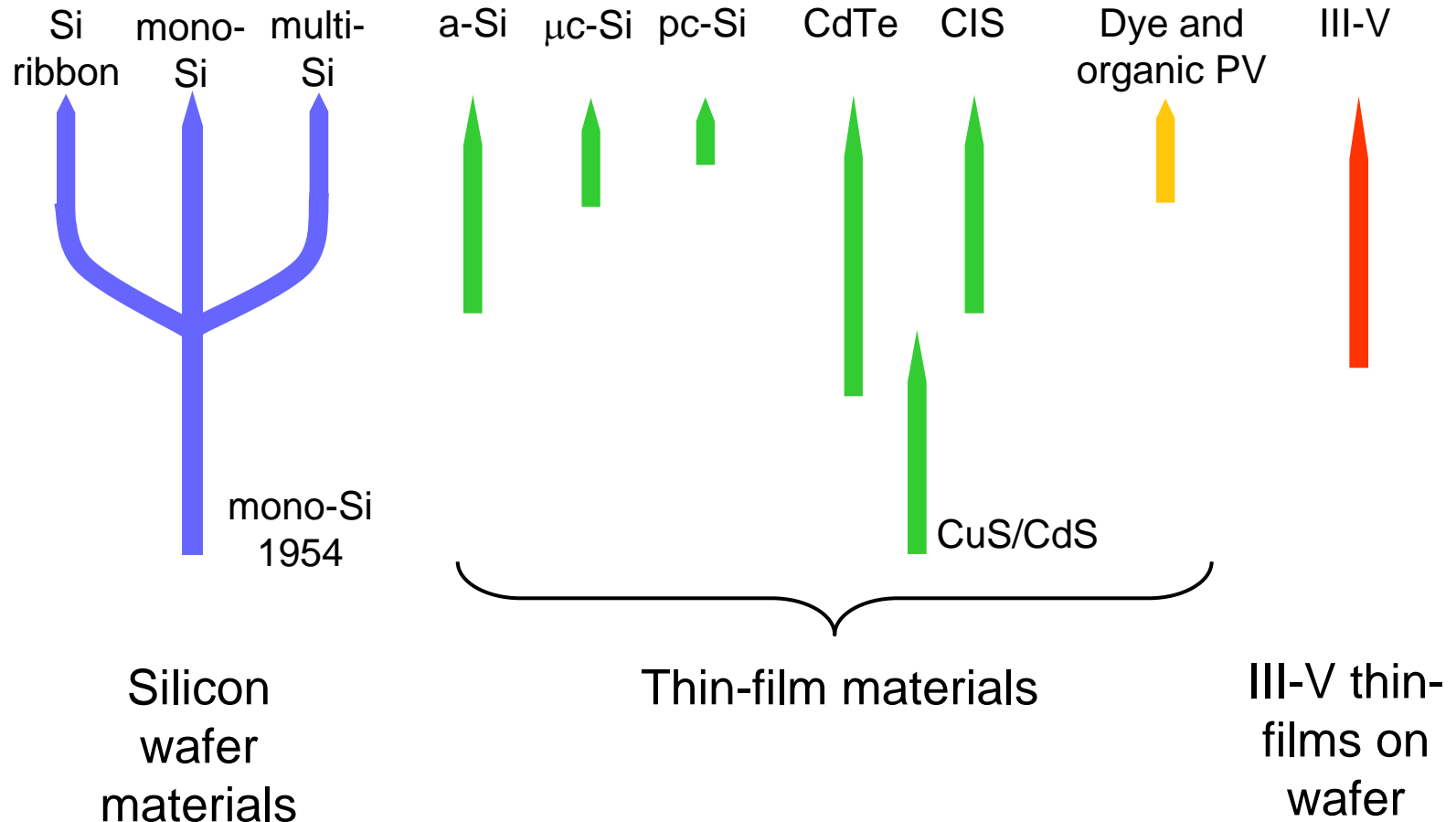


Global PV market



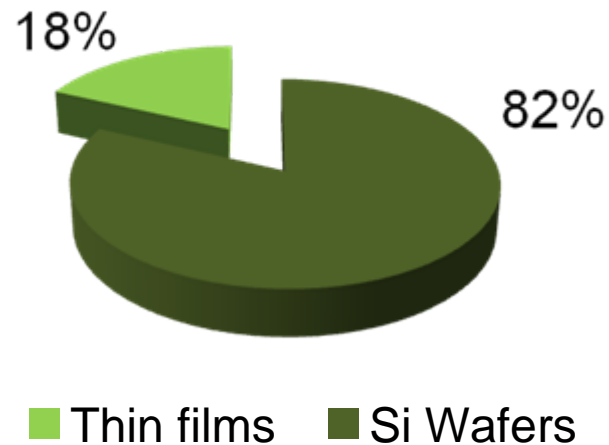
Source: EPIA

Materials for PV energy conversion

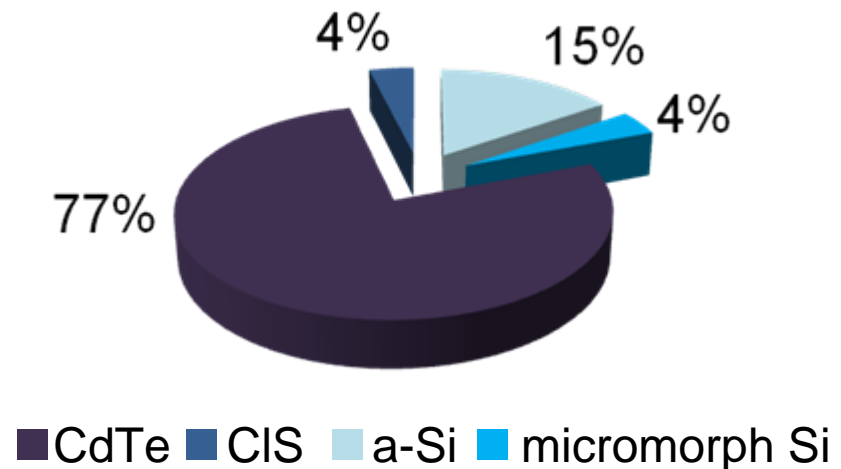


Market shares of PV technologies

Total PV market in 2009



Thin film PV market in 2009



Efficiencies of major PV technologies

Technology	Best Eff in lab (cells)	Eff in industry (modules)	Remarks
Mono-Si	25.0%	14-20%	Pseudo-square wafers (125 mm)
Multi-Si	20.4%	13-18%	Square wafers (156 mm)
CIS (CIGS)	20.1%	9-13%	Uses indium (scarce)
CdTe	16.7%	9-11%	Uses tellurium (scarce)
Micromorph Si	11.7%	7-10%	Tandem cell (a-Si/ μ c-Si)
Amorphous Si	10.1%	5-7%	Very thin cell (Si ~300 nm)

Silicon wafer photovoltaics

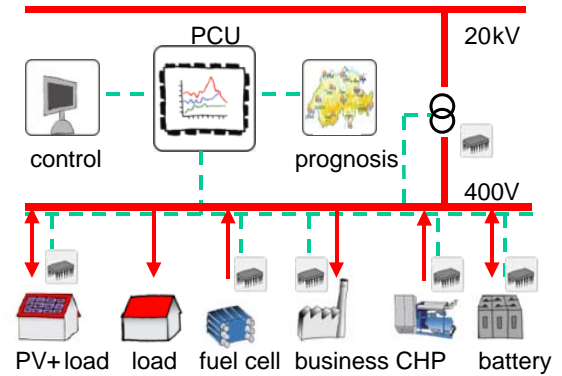
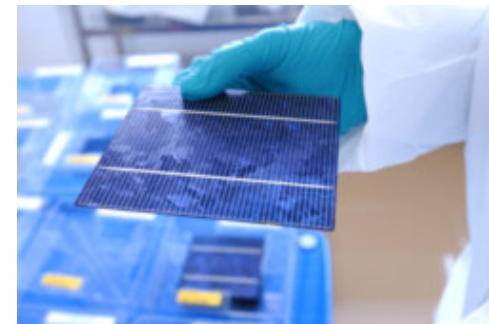
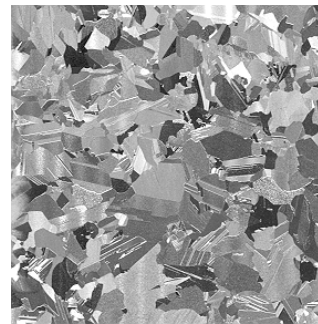
Status 2010



- ❑ Production of silicon wafer PV is growing rapidly ($> 30\%$ p.a.)
- ❑ Module efficiencies 13 - 20 %
- ❑ Proven technical lifetime of > 20 years
- ❑ Applications: All market segments, in particular those with limited space availability (high efficiency required)

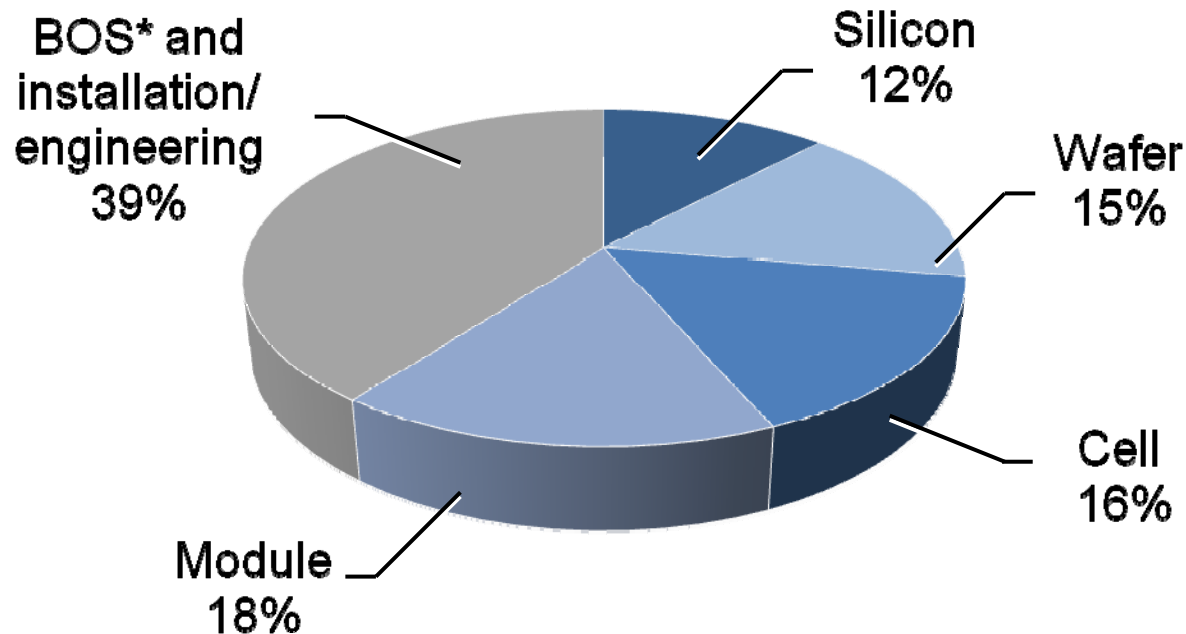
Silicon wafer photovoltaics

Industrial sectors of silicon wafer PV



Silicon wafer photovoltaics

Cost breakdown of Si wafer based PV system, 2009



* BOS – balance of system (inverters, mounting system, cabling, etc)

Sources: Barclays Capital, industry sources, SERIS market research 2010

Thin-film photovoltaics

Status 2010

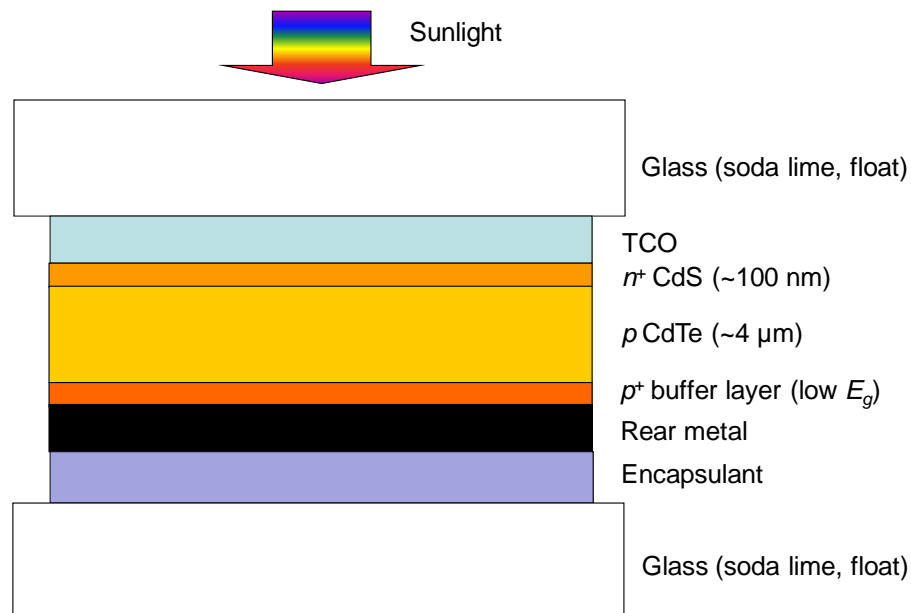


- ❑ Thin-film PV production is growing rapidly (> 30% p.a.)
- ❑ Module efficiencies 5 - 13 %
- ❑ Semiconductor material consumption is about 100 times lower compared to Si wafer PV
- ❑ Warranted technical lifetime of 20 years
- ❑ Main applications: Green-field power plants, BIPV

Thin-film photovoltaics

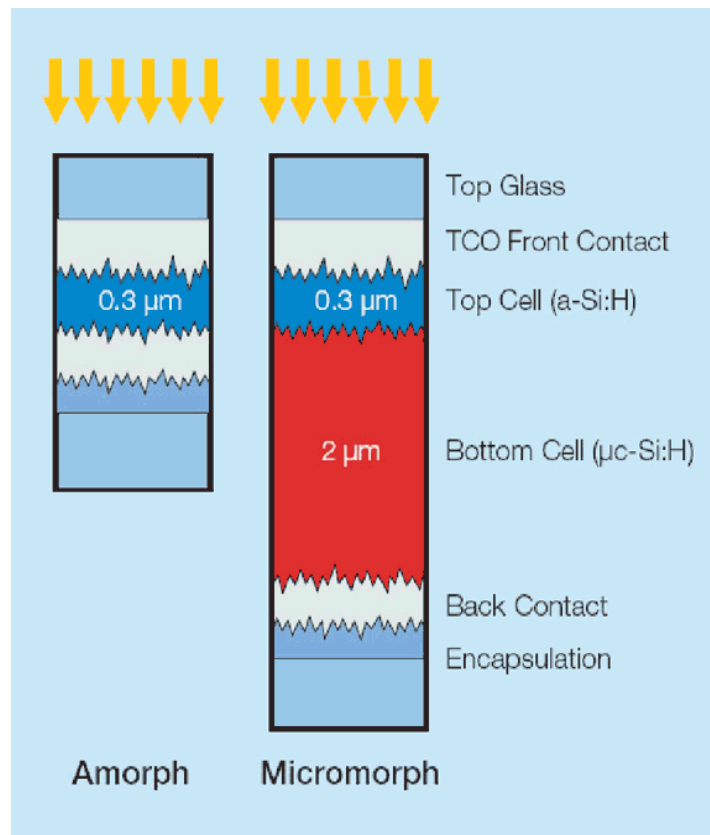
Example: Cadmium telluride technology

- ❑ Process: Clean front glass → TCO → Scribe 1 → CdS window layer (heterojunction) → CdTe absorber (~4 μm) → Activation step (annealing at ~450°C in CdCl_2) → Scribe 2 → Back contact → Scribe 3 → Rear glass
- ❑ Entire process takes less than 3 hours



Thin-film photovoltaics

Example: Micromorph silicon technology



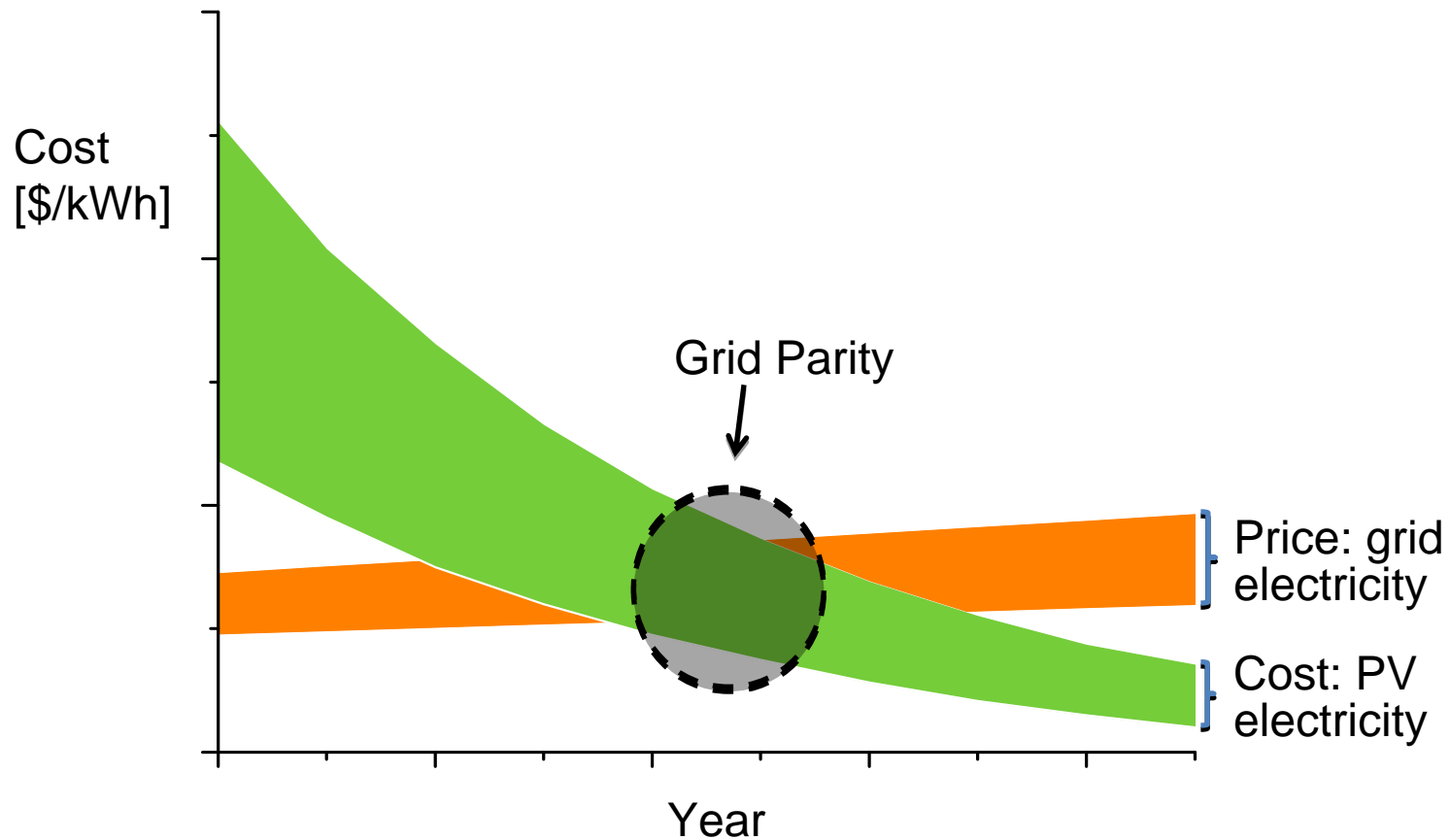
- ❑ University of Neuchatel, 1994: Efficient a-Si/μc-Si tandem solar cell on a soda-lime glass superstrate
- ❑ Voltages of up to 1.4 V
- ❑ Concept has been taken up by industry (Kaneka, Sharp, Bosch, ...)
- ❑ Turn-key lines for micromorph PV modules available

Source: Oerlikon Solar

Summary

- ❑ PV is booming (growth > 30% per year)
- ❑ Costs of PV modules:
 - Have been halved in the last 5 years
(Si wafer modules now cost ~2 USD/W_p, thin-films ~25% less)
 - Likely to be halved again during this decade
- ❑ Silicon wafer based technologies will very likely remain the locomotive of the PV sector during the next 10 years
- ❑ Thin-film based technologies are gaining momentum:
 - CdTe will very likely remain strong during this decade
 - Upscaling of CIGS and micromorph is underway
- ❑ Also: Optical concentrator PV is gaining momentum

Grid parity in photovoltaics



Thank you for your attention!

More information at www.seris.sg